Low-Power, Low-Drift, Low-Noise Voltage Reference

General Description

The MAX6078 precision voltage reference family provides low drift and low noise at a maximum power supply current of only 15µA. Low-frequency noise is less than $12\mu V_{P-P}$ (2.5V output voltage option) and the temperature coefficient of the output voltage is less than 10ppm/°C.

The reference output can sink and source up to 3mA of load current and the top grade provides an initial accuracy of 0.04%. The low-drift and low-noise specifications enable enhanced system accuracy, making these devices ideal for high-precision industrial applications. A noise reduction (NR) input pin allows connection of an external capacitor to reduce wideband noise. Available output voltages include 1.25V, 2.048V, 2.5V, 3.0V, 3.3V, 4.096V, and 5.0V.

The tiny, 6-bump WLP and small, 8-pin TDFN-EP packages are suitable for systems where circuit board area is limited. The operating input voltage can range from 2.3V to 5.5V. Operation is specified over the extended industrial temperature range of -55°C to +125°C.

IN

BANDGAP

NR

FN

MAX6078

GND

-^^^

OUTS

OUTE

Applications

- High-Accuracy Industrial and Process Control
- Precision Instrumentation
- High-Resolution ADCs and DACs
- Portable and Handheld Systems

Simplified Block Diagram

Benefits and Features

- ±0.04% Initial Accuracy
- 10ppm/°C (max) Temperature Drift
- 12µV_{P-P} Noise (0.1Hz to 10Hz) at 2.5V
- 15µA Supply Current
- Long-Term Drift: 16ppm (typ, 4000hrs)
- 3mA Source/Sink Load Current
- Filter Option Reduces High-Frequency Noise
- 100mV Dropout Voltage
- 1.5mm x 1.3mm (0.5mm pitch), 6-Bump WLP and 2mm x 3mm, 8-Pin TDFN-EP Packages
- Voltage Output Options: 1.25V, 2.048V, 2.5V, 3.0V, 3.3V, 4.096V, and 5.0V

Ordering Information appears at end of data sheet.



Low-Power, Low-Drift, Low-Noise Voltage Reference

TABLE OF CONTENTS

General Description
Applications
Benefits and Features
Simplified Block Diagram 1
Absolute Maximum Ratings 4
Package Information
8 TDFN
8 WLP
Electrical Characteristics – 2.5V
Electrical Characteristics – 3.0V
Electrical Characteristics – 3.3V
Typical Operating Characteristics
Pin Configurations
6 WLP
8 TDFN-EP
Pin Description
Typical Operating Circuit
Detailed Description
Wideband Noise Reduction (NR) 14
Output Bypassing
Turn-On Time
Output Force and Sense
Shutdown
Thermal Hysteresis 14
Applications Information
Precision Current Source
Ordering Information
Revision History

Low-Power, Low-Drift, Low-Noise Voltage Reference

LIST OF FIGURES

Figure 1. Noise Reduction Capacitor	14
Figure 2. Precision Current Source	15

Low-Power, Low-Drift, Low-Noise Voltage Reference

Absolute Maximum Ratings

OUTF to GND	0.3V to (V _{IN} + 0.3)V
IN to GND	
EN to GND	
NR to GND	0.3V to (V _{IN} + 0.3)V
Current to/from OUTF	
Current to/from OUTS/NR/EN	

Maximum Continuous Power Dissipation (T _A =	+70°C).
TDFN (derate 16.7mW/°C above +70°C)	1333.3mW
WLP (derate 12.34mW/°C above +70°C)	987.2mW
Operating Temperature Range	55°C to +125°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C
Soldering Temperature (reflow)	+260°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Package Information

8 TDFN

Package Code	T823+1C
Outline Number	<u>21-0174</u>
Land Pattern Number	<u>90-0091</u>
Thermal Resistance, Four-Layer Board	
Junction to Ambient (θ_{JA})	60°C/W
Junction to Case (θ_{JC})	11°C/W

8 WLP

Package Code W61L1+1					
Outline Number 21-100365					
Land Pattern Number Refer to Application Note 1891					
Thermal Resistance, Four-Layer Board					
Junction to Ambient (θ _{JA})	81.03°C/W				
Junction to Case (θ_{JC})	N/A				

For the latest package outline information and land patterns (footprints), go to <u>www.maximintegrated.com/packages</u>. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to <u>www.maximintegrated.com/</u> <u>thermal-tutorial</u>.

Electrical Characteristics – 2.5V

 $(V_{IN} = +3.3V, I_{OUT} = 0mA, C_{OUT} = 0.1\mu$ F, T_A = -55°C to +125°C, unless otherwise specified. Typical values are at T_A = +25°C (<u>Note</u> <u>1</u>))

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Output Voltage Accuracy		T _A = +25°C	-0.04		+0.04	%
Output Voltage	TCV	-40°C to +125°C (<u>Note 2</u>)		2	10	nnm/°C
Temperature Drift	TCV _{OUT}	-55°C to +125°C (<u>Note 2</u>)		2	10	ppm/°C

Low-Power, Low-Drift, Low-Noise Voltage Reference

Electrical Characteristics – 2.5V (continued)

 $(V_{IN} = +3.3V, I_{OUT} = 0mA, C_{OUT} = 0.1\muF, T_A = -55^{\circ}C \text{ to } +125^{\circ}C, \text{ unless otherwise specified. Typical values are at T_A = +25^{\circ}C (<u>Note 1</u>))$

PARAMETER	SYMBOL	CON	MIN	TYP	MAX	UNITS		
Line Regulation		Over specified oper range		10	175	μV/V		
Load Regulation		$-3mA \le I_{OUT} \le +3m$		5	125	μV/mA		
DropoutValtage		I _{OUT} = 3mA (<u>Note</u>	<u>3</u>)			100		
Dropout Voltage		I _{OUT} = 100μA (<u>Not</u>	<u>e 3</u>)			10	- mV	
Output Current	IOUT	Guaranteed by load	d regulation	-3		+3	mA	
Ohart Oireuit Ourreat		Sourcing to ground			36			
Short-Circuit Current	Isc	Sinking current fror	n V _{IN}		24		- mA	
			0 to 4000hrs		16			
			0 to 1000hrs		9.8			
Long-Term Stability		T _A = +35°C	1000hrs to 2000hrs		2.5		ppm	
			2000hrs to 3000hrs		1.89			
			3000hrs to 4000hrs		1.96			
Thermal Hysteresis		(<u>Note 4</u>)	·		20		ppm	
		0.1Hz to 10Hz, CO	_{UT} = 0.1μF		12		μV _{P-P}	
Output Noise Voltage	e _{OUT}	10Hz to 10kHz, C _{OUT} = 0.1µF			30			
		10Hz to 10kHz, C _C 0.01µF	_{UT} = 0.1µF, C _{NR} =		20		μV _{RMS}	
Dutput Noise Spectral		f = 100Hz, C _{OUT} =	0.1µF		580			
Density		f = 100Hz, C _{OUT} =	0.1µF, C _{NR} = 0.01µF	385			nV/√Hz	
Ripple Rejection		f = 60Hz			50		dB	
Turn-On Settling Time		Settling to 0.1%, $C_{OUT} = 0.1 \mu F$	C _{NR} = 0.01µF		50			
		Settling to 0.1%, $C_{OUT} = 0.1 \mu F$	No C _{NR}		5		- ms	
Enable Sottling Time	+	Settling to 0.1%, $C_{OUT} = 0.1 \mu F$	C _{NR} = 0.01µF		30		ma	
Enable Settling Time	t _{EN}	Settling to 0.1%, $C_{OUT} = 0.1 \mu F$	No C _{NR}		3		- ms	
Capacitive-Load Stability Range				0.1		4.7	μF	
Supply Voltage	V _{IN}			2.7		5.5	V	

Low-Power, Low-Drift, Low-Noise Voltage Reference

Electrical Characteristics – 2.5V (continued)

 $(V_{IN} = +3.3V, I_{OUT} = 0mA, C_{OUT} = 0.1\muF, T_A = -55^{\circ}C \text{ to } +125^{\circ}C, \text{ unless otherwise specified. Typical values are at T_A = +25^{\circ}C (<u>Note 1</u>))$

PARAMETER	SYMBOL	C	ONDITIONS	MIN	TYP	MAX	UNITS
			T _A = +25°C		10	15	
		V _{IN} = 5V	T _A = -55°C to +85°C			16.5	
Quiescent Supply	L.		T _A = -55°C to +125°C			18	- μΑ
Current	lin	V _{IN} = 3.3V	T _A = +25°C		9	14	
			T _A = -55°C to +85°C			15.5	
			T _A = -55°C to +125°C			17	
Shutdown Supply Current	I _{SD}				0.1	2	μA
Enable Input Current	I _{EN}					0.1	μA
Enable Logic-High	VIH			0.7 x V _{IN}			V
Enable Logic-Low	VIL					0.3 x V _{IN}	V

Electrical Characteristics – 3.0V

 $(V_{IN} = +5V, I_{OUT} = 0mA, C_{OUT} = 0.1 \mu F, T_A = -55^{\circ}C$ to $+125^{\circ}C$, unless otherwise specified. Typical values are at $T_A = +25^{\circ}C$ (*Note 1*))

PARAMETER	SYMBOL	CC	NDITIONS	MIN	TYP	MAX	UNITS	
Output Voltage Accuracy		T _A = +25°C	-0.04		+0.04	%		
Output Voltage	TCV	-40°C to +125°C	(<u>Note 2</u>)		2	10	nnm/°C	
Temperature Drift	TCV _{OUT}	-55°C to +125°C	(<u>Note 2</u>)		2	10	ppm/°C	
Line Regulation		Over specified or range	Over specified operating input voltage range		10	175	μV/V	
Load Regulation		-3mA ≤ I _{OUT} ≤ +3	3mA		5	125	μV/mA	
Dropout Voltage		I _{OUT} = 3mA (<u>Note 3</u>) I _{OUT} = 100μA (<u>Note 3</u>)			100 10	100	- mV	
						10		
Output Current	I _{OUT}	Guaranteed by lo	Guaranteed by load regulation			+3	mA	
Short-Circuit Current	1	Sourcing to ground			36		m 4	
Short-Circuit Current	Isc	Sinking current from VIN			24		mA	
			0 to 4000hrs		16			
			0 to 1000hrs		9.8			
Long-Term Stability		T _A = +35°C	1000hrs to 2000hrs		2.5		ppm	
			2000hrs to 3000hrs		1.89			
			3000hrs to 4000hrs		1.96			
Thermal Hysteresis		(<u>Note 4</u>)			20		ppm	

Low-Power, Low-Drift, Low-Noise Voltage Reference

Electrical Characteristics – 3.0V (continued)

PARAMETER	SYMBOL	CON	DITIONS	MIN	TYP	MAX	UNITS
		0.1Hz to 10Hz, C _{OUT} = 0.1µF			12		μV _{P-P}
Output Noise Voltage	0.0.1.7	10Hz to 10kHz, C _{OUT} = 0.1µF			30		
Output Noise Voltage	6001	e_{OUT} 10Hz to 10kHz, $C_{OUT} = 0.1 \mu$ F, $C_{NR} = 0.01 \mu$ F			20		μV _{RMS}
Output Noise Spectral		f = 100Hz, C _{OUT} = 0.1µF			580		nV/√Hz
Density		f = 100Hz, C _{OUT} =	0.1µF, C _{NR} = 0.01µF		385		
Ripple Rejection		f = 60Hz			50		dB
Turn-On Settling Time		Settling to 0.1%, $C_{OUT} = 0.1 \mu F$	C _{NR} = 0.01µF		50		
		Settling to 0.1%, $C_{OUT} = 0.1 \mu F$	No C _{NR}		5		ms
Enable Settling Time	t _{EN}	Settling to 0.1%, C _{OUT} = 0.1µF	C _{NR} = 0.01µF		30		ma
		Settling to 0.1%, $C_{OUT} = 0.1 \mu F$	No C _{NR}	3		- ms	
Capacitive-Load Stability Range				0.1		4.7	μF
Supply Voltage	V _{IN}			3.2		5.5	V
		T _A = +25°C			10	15	
Quiescent Supply Current	I _{IN}	T _A = -55°C to +85°C				16.5	μA
Current		T _A = -55°C to +125°C				18	
Shutdown Supply Current	I _{SD}				0.1	2	μA
Enable Input Current	I _{EN}					0.1	μA
Enable Logic-High	VIH			0.7 x V _{IN}			V
Enable Logic-Low	VIL					0.3 x V _{IN}	V

Electrical Characteristics – 3.3V

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
Output Voltage Accuracy		T _A = +25°C	-0.04		+0.04	%	
Output Voltage	TOV	-40°C to +125°C (<u>Note 2</u>)		2 10			
Temperature Drift	TCV _{OUT}	-55°C to +125°C (<u>Note 2</u>)		2	10	ppm/°C	
Line Regulation		Over specified operating input voltage range		10	175	μV/V	
Load Regulation		$-3mA \le I_{OUT} \le +3mA$		5	125	μV/mA	
Dropout Voltage		I _{OUT} = 3mA (<u>Note 3</u>)			100	mV	
		I _{OUT} = 100μA (<u>Note 3</u>)			10	IIIV	
Output Current	IOUT	Guaranteed by load regulation	-3		+3	mA	

Low-Power, Low-Drift, Low-Noise Voltage Reference

Electrical Characteristics – 3.3V (continued)

(VIN = +5V, IOUT = 0mA, COUT = 0.1µF, T_A = -55°C to +125°C, unless otherwise specified. Typical values are at T_A = +25°C (Note 1))

PARAMETER	SYMBOL	CON	DITIONS	MIN	TYP	MAX	UNITS	
Ohart Oireuit Ourrest	Isc	Sourcing to ground			36			
Short-Circuit Current		Sinking current from V _{IN}			24		– mA	
			0 to 4000hrs		16			
			0 to 1000hrs		9.8		ppm	
Long-Term Stability		T _A = +35°C	1000hrs to 2000hrs		2.5			
			2000hrs to 3000hrs		1.89		-	
			3000hrs to 4000hrs		1.96			
Thermal Hysteresis		(<u>Note 4</u>)	1		20		ppm	
	eout	0.1Hz to 10Hz, C _{OUT} = 0.1µF			12		μV _{P-P}	
Output Noise Voltage		10Hz to 10kHz, C _{OUT} = 0.1µF			30		μV _{RMS}	
		10Hz to 10kHz, C _{OUT} = 0.1µF, C _{NR} = 0.01µF			20			
Output Noise Spectral		f = 100Hz, C _{OUT} =	0.1µF	580			nV/√Hz	
Density		f = 100Hz, C _{OUT} = 0.1µF, C _{NR} = 0.01µF		385		- nv/vHz		
Ripple Rejection		f = 60Hz		50		dB		
Turn-On Settling Time		Settling to 0.1%, C _{OUT} = 0.1µF	C _{NR} = 0.01µF		50			
		Settling to 0.1%, C _{OUT} = 0.1µF	No C _{NR}		5		ms	
Enable Settling Time	t _{EN}	Settling to 0.1%, C _{OUT} = 0.1µF	C _{NR} = 0.01µF		30		– ms	
		Settling to 0.1%, $C_{OUT} = 0.1 \mu F$	No C _{NR}		3			
Capacitive-Load Stability Range			·	0.1		4.7	μF	
Supply Voltage	V _{IN}			3.5		5.5	V	
Quiescent Supply Current	I _{IN}	$T_A = +25^{\circ}C$			10	15		
		T _A = -40°C to +125°C				16.5	μA	
		T _A = -55°C to +125°C				18		
Shutdown Supply Current	I _{SD}				0.1	2	μA	
Enable Input Current	I _{EN}					0.1	μA	
Enable Logic-High	VIH			0.7 x V _{IN}			V	
Enable Logic-Low	VIL					0.3 x V _{IN}	V	

Note 1: Limits are 100% tested at $T_A = +25$ °C. Limits over the operating temperature range and relevant supply voltage range are guaranteed by design and characterization.

Note 2: Temperature coefficient is calculated using the "box method" which measures temperature drift as the maximum voltage variation over a specified temperature range.

Note 3: Dropout voltage is defined as the minimum differential voltage ($V_{IN} - V_{OUT}$) at which V_{OUT} decreases by 0.2% from its original value. V_{IN} = 3.3V for output voltages of 1.25V, 2.048V, and 2.5V; V_{IN} = 5V for output voltages of 3V, 3.3V, 4.096V; V_{IN} = 5.5V for output voltage of 5V.

Note 4: Thermal hysteresis is defined as the change in +25°C output voltage before and after cycling the device from T_{MAX} to T_{MIN}.

Low-Power, Low-Drift, Low-Noise Voltage Reference

Typical Operating Characteristics

(V_{IN} = 3.3V, I_{OUT} = 0mA, C_{OUT} = 0.1 μ F to GND, T_A = +25°C, unless otherwise noted.)















QUIESCENT SUPPLY CURRENT

vs. SUPPLY INPUT VOLTAGE

₄ = +125°C

T_A = +25°C

r_A = -55°C

4 4.5

SUPPLY INPUT VOLTAGE (V)

T_A = -40°C

5

55

12

11

10

9

8

7

6

5

25

3

3.5

QUIESCENT SUPPLY CURRENT (µA)

LOAD REGULATION





SHUTDOWN SUPPLY CURRENT vs. SUPPLY INPUT VOLTAGE



Low-Power, Low-Drift, Low-Noise Voltage Reference

Typical Operating Characteristics (continued)

(V_{IN} = 3.3V, I_{OUT} = 0mA, C_{OUT} = 0.1 μ F to GND, T_A = +25°C, unless otherwise noted.)





TURN-ON TRANSIENT (C_{NR} = NO LOAD)





MAX6078_25+ DUTPUT IMPEDANCE vs. FREQUENCY





MAX6078_25+ VOLTAGE NOISE DENSITY vs. FREQUENCY



LOAD-TRANSIENT RESPONSE (C_{NR} = NO LOAD)



Low-Power, Low-Drift, Low-Noise Voltage Reference

Typical Operating Characteristics (continued)

(V_{IN} = 3.3V, I_{OUT} = 0mA, C_{OUT} = 0.1 μ F to GND, T_A = +25°C, unless otherwise noted.)













ENABLE THRESHOLD vs. TEMPERATURE

1.9



Low-Power, Low-Drift, Low-Noise Voltage Reference

Pin Configurations

6 WLP



8 TDFN-EP



Low-Power, Low-Drift, Low-Noise Voltage Reference

Pin Description

PIN 6 WLP 8 TDFN-EP		NAME	FUNCTION		
		NAME			
A1	5	OUTS	Voltage Reference Output Sense. Connect OUTF and OUTS as close as possible to the load.		
A2	6	OUTF	Voltage Reference Force Output. Connect OUTF and OUTS as close as possible to the load. Bypass OUTF with a capacitor to GND.		
A3	7	NR	Noise Reduction Input. Connect a 0.01µF capacitor from NR to ground to provide wideband noise filtering. Leave unconnected if not used.		
B1	4	GND	Ground		
B2	2	IN	Supply Input		
B3	1	EN	Enable. Drive high to enable. Drive low to disable.		
_	3, 8	NC	No Connect. Not internally connected. May be connected to GND.		
	EP	EP	Exposed Pad. EP is internally connected to GND. Connect EP to GND.		

Typical Operating Circuit



Detailed Description

Wideband Noise Reduction (NR)

To improve wideband noise and transient power supply noise, connect a 0.01μ F capacitor from NR to GND (see the <u>Typical Operating Characteristics</u>). Larger values do not appreciably improve noise reduction. A 0.01μ F capacitor reduces the spectral noise density at 100Hz from 580nV/ \sqrt{Hz} to 385nV/ \sqrt{Hz} for the 2.5V output version. Noise at the input pin can affect output noise, but can be reduced by connecting an optional bypass capacitor between IN and GND, as shown in Figure 1.



Figure 1. Noise Reduction Capacitor

Output Bypassing

Use an output capacitor with a value between 0.1μ F and 4.7μ F. Place the output capacitor as close to OUTF as possible. For applications driving switching capacitive loads or rapidly changing load currents, use a 0.1μ F capacitor in parallel with a larger load capacitor to reduce equivalent series resistance (ESR). Larger capacitor values and lower ESR reduce transients on the reference output.

Turn-On Time

These references typically turn on and settle to within 0.1% of their final value in 5ms with no capacitive loads at NR pin. A 0.1μ F load capacitor at OUTF and a 0.01μ F noise reduction capacitor connected to the NR input increase the turn-on time to approximately 50ms.

Output Force and Sense

These references provide independent connections for the force output (OUTF), which supplies current to the load and the feedback input that regulates the load voltage through the output sense pin (OUTS). This configuration allows for the cancellation of the voltage drop on the lines connecting the reference to the load. Connect OUTF to the load and connect OUTS to OUTF at the point where the voltage accuracy is needed (Figure 1).

Shutdown

Although the operating power supply current of these references is very low, there are some cases that require even lower supply current during shutdown conditions. Pulling EN low disables the output with an internal resistive load to ground and forces the quiescent current to less than 100nA. Pulling EN high enables normal operation. The return to normal operation occurs within the 3ms enable time delay typically.

Thermal Hysteresis

Thermal hysteresis is the change of output voltage at $T_A = +25^{\circ}C$ before and after the device is cycled over its entire operating temperature range. The typical thermal hysteresis value is 20ppm.

Applications Information

Precision Current Source

<u>Figure 2</u> shows a precision current source. The OUTF output provides the bias current for the bipolar transistor. OUTS and GND sense the voltage across the resistor and adjust the current sourced by OUTF accordingly. The voltage range of OUTF is set by the reference output voltage (OUTS) and the V_{BE} (BJT) of the output external device:

 $V_{OUTF} = V_{BE} + V_{REF}$

where:

VOUTF is the voltage on the OUTF pin,

V_{BE} is the base-emitter drop across BJT,

V_{REF} is the actual voltage reference output this part is supposed to provide.

Therefore, the input supply voltage requirement for the MAX6078 is as follows:

 $V_{IN} \ge V_{DROP}$ (dropout voltage) + $V_{BE}max + V_{REF}$

where:

V_{DROP} is the dropout voltage of the voltage reference.



Figure 2. Precision Current Source

Low-Power, Low-Drift, Low-Noise Voltage Reference

Ordering Information

PART NUMBER	TEMP RANGE	PIN-PACKAGE	V _{OUT} (V)	ACCURACY (%)	TOP MARK
MAX6078BMWT12+T*	-55°C to +125°C	6 WLP	1.250	0.04	_
MAX6078AMWT21+T*	-55°C to +125°C	6 WLP	2.048	0.04	—
MAX6078AMWT25+T	-55°C to +125°C	6 WLP	2.500	0.04	+AAE
MAX6078AMWT30+T	-55°C to +125°C	6 WLP	3.000	0.04	+AAH
MAX6078AMWT33+T	-55°C to +125°C	6 WLP	3.300	0.04	+AAI
MAX6078AMWT41+T*	-55°C to +125°C	6 WLP	4.096	0.04	_
MAX6078AMWT50+T*	-55°C to +125°C	6 WLP	5.000	0.04	—
MAX6078BMTA12+T*	-55°C to +125°C	8 TDFN-EP	1.250	0.04	—
MAX6078AMTA21+T*	-55°C to +125°C	8 TDFN-EP	2.048	0.04	_
MAX6078AMTA25+T*	-55°C to +125°C	8 TDFN-EP	2.500	0.04	—
MAX6078AMTA30+T*	-55°C to +125°C	8 TDFN-EP	3.000	0.04	_
MAX6078AMTA33+T*	-55°C to +125°C	8 TDFN-EP	3.300	0.04	
MAX6078AMTA41+T*	-55°C to +125°C	8 TDFN-EP	4.096	0.04	
MAX6078AMTA50+T*	-55°C to +125°C	8 TDFN-EP	5.000	0.04	

+ Denotes a lead(Pb)-free/RoHS-compliant package.

T = Tape and reel.

*Future product—contact factory for availability.

Low-Power, Low-Drift, Low-Noise Voltage Reference

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	6/19	Initial release	—
1	9/20	Updated Benefits and Features, Electrical Characteristics, Typical Operating Characteristics, and Ordering Information table	1, 4, 5, 7–9, 14
2	3/21	Updated the Electrical Characteristics and Ordering Information tables	6–8, 16

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